Silicon N-Channel MOS FET

HITACHI

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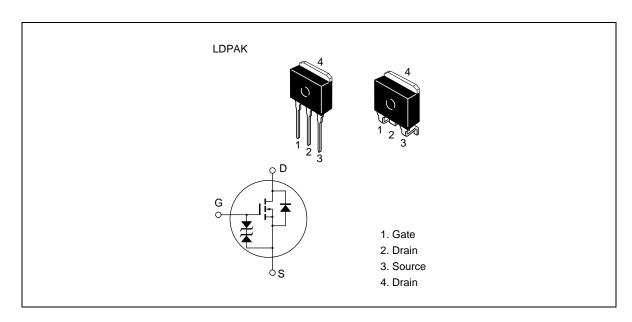
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

Outline



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	900	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	4	A
Drain peak current	l _{D(pulse)} *1	10	A
Body to drain diode reverse drain current	I _{DR}	4	A
Channel dissipation	Pch*2	60	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes 1. PW \leq 10 μ s, duty cycle \leq 1%

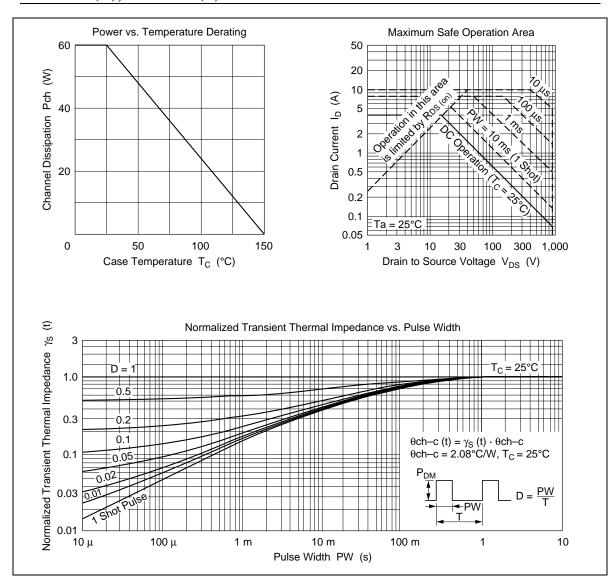
2. Value at $T_c = 25^{\circ}C$

Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	900	_	_	V	$I_{D} = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	_	_	V	$I_{_{G}} = \pm 100 \ \mu A, \ V_{_{DS}} = 0$
Gate to source leak current	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	250	μΑ	$V_{DS} = 720 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{\text{GS(off)}}$	2.0	_	3.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static Drain to source on state resistance	R _{DS(on)}	_	3.0	4.0	Ω	$I_{D} = 2 \text{ A}, V_{GS} = 10 \text{ V}^{*1}$
Forward transfer admittance	yfs	1.7	2.7	_	S	$I_D = 2 \text{ A}, V_{DS} = 20 \text{ V}^{*1}$
Input capacitance	Ciss	_	740	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	305	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	150	_	pF	
Turn-on delay time	t _{d(on)}	_	15	_	ns	$I_D = 2 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time	t _r	_	60	_	ns	$R_L = 15 \Omega$
Turn-off delay time	t _{d(off)}		100	_	ns	
Fall time	t _f		80	_	ns	
Body to drain diode forward voltage	V_{DF}	_	0.9	_	V	$I_{F} = 4 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	_	800	_	ns	$I_F = 4 \text{ A}, V_{GS} = 0,$ $di_F/dt = 100 \text{ A/}\mu\text{s}$
						

Note 1. Pulse test

See characteristic curves of 2SK1340.



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